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XRD AND XPS STUDIES OF SURFACE MMC LAYERS DEVELOPED BY LASER ALLOYING Ti-6Al-4V USING A COMBINATION OF A DILUTE NITROGEN ENVIRONMENT AND SiC POWDER

M. S. Selamat¹, L. M. Watson² and T. N. Baker²

1 Advanced Materials Research Centre (AMREC), SIRIM Berhad

1 Persiaran Dato Menteri, P. O. Box 7035, Section 2

40911 Shah Alam, Malay

2 Metallurgy and Engineering Materials Group, Department of Mechanical

Engineering

University of Strathclyde, Glasgow G1 1XN, U.K.

Corresponding author: Professor T.N.Baker, Metallurgy and Engineering Materials Group,

Department of Mechanical Engineering, University of Strathclyde, Glasgow G1 1XN, U.K.

Phone:01415483101, Fax: 01415525105, e-mail; neville.baker@strath.ac.uk

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ABSTRACT

Using a continuous-wave CO₂ laser, surface engineering of a Ti-6Al-4V alloy through a combined treatment of laser nitriding and SiC preplacement was undertaken. Under spinning laser beam conditions, a surface alloyed / metal matrix composite (MMC) layer over 300µm in depth and 24mm wide was produced in the alloy by the overlapping of 12 tracks.

Microstructural and chemical changes were studied as a function of (a) depth in the laser formed composite layer and (b) of the track position. Using X- ray diffraction (XRD) and X- ray photospectrographic (XPS) techniques, it was shown that the composite layer contained a complex microstructure which changed with depth. At the surface, a non-stoichiometric, cubic TiN_x solid solution (possibly a carbonitride) containing C and Si , where $x \approx 0.65-0.8$, was prominent, but was replaced by α' -Ti with increasing depth to 300µm. TiC phase was also identified, and the presence of TiN_{0.3} and Ti₅Si₃ phases considered a distinct possibility.

Keywords Laser surface engineering, Titanium alloy, X-ray diffraction, Photoelectron spectroscopy,
Lattice parameters.

1 INTRODUCTION

Laser surface nitriding is a technique for modifying the near-surface region of alloys without altering the bulk characteristics. This technique has been developed over the past 20 years and involves the use of the intense optical energy of the laser to melt the surface in a nitrogen-containing atmosphere [1-10]. While hardness values in excess of 2000VHN with melt depths around 1mm have been reported, the nitrided surface invariably contained cracks.

The development of crack-free TiN surfaces was achieved by diluting the nitrogen content for laser treated commercially pure titanium (CPTi), as reported by Mridha and Baker [5], and for Ti-6Al-4V by Selamat et al [10]. However, this proved to be at the expense of both a lower hardness and a shallower melt depth.

An alternative means of developing a deep hard surface layer is to produce a surface MMC [11-15]. The early work in this area reported the injection of 30-50 vol.-% of $\sim 100\mu\text{m}$ size particles of TiC into the laser melted surface of titanium alloys [11, 12]. This gave a hardness value, measured between the embedded particles, of 450VHN. Abboud and West [13] injected $150\mu\text{m}$ particles of SiC powder into a commercially pure titanium surface. They observed partial dissolution of the particles, which led to the enrichment of the matrix with silicon and carbon during solidification. Both TiC and Ti_5Si_3 phases were formed, and the hardness increased from 210 to 600VHN. A further development was made with the aim of completely dissolving the preplaced particles 3 to $7\mu\text{m}$ in size, a size chosen to facilitate dissolution, [14-15]. The resulting surfaces showed a hardness for the first $100\mu\text{m}$ below the surface, of 1000-1400VHN, followed by a plateau of hardness in the range 450-550VHN, extending to a depth of about $500\mu\text{m}$. The large change in hardness was associated with the formation of TiC

during the laser melting, which was undertaken in a protective atmosphere of argon or helium. Another advantage of alloying with SiC, is that Si in solid solution extends the liquid phase to lower temperatures, reducing the possibility of cracking. A logical extension of these two approaches was to combine them to explore the possibility of gaining the advantage of both nitriding in a dilute environment and fine particle formation via alloying with carbide or nitride particles. Using this technique it was hoped to increase the melt depth and the hardness, while avoiding cracking. This approach was initially undertaken using a commercially pure titanium alloy with 6 μ m preplaced SiC powder [16]. The results were very promising and did achieve the objectives given above. Several compounds, including ZrC and ZrN and a mixture of SiC and Ti-6Al-4V powders were considered as possible improvements on SiC. The laser nitriding was carried out on a Ti-6Al-4V alloy base, again with a single melt track.[17].Due to the limitations on the availability of the particle sizes of the Zr compounds, the preplaced particles were of an average size of \sim 45 μ m. The new surfaces were subjected to room temperature abrasive wear testing to rank the resistance of the surfaces to this kind of wear. The SiC treated surfaces showed by far the best abrasive wear resistance.

While much of the laser surface engineering discussed in the literature refers to either spot or single track melting, there are many occasions when the laser processing of a surface requires an area to be treated and therefore many overlapping melt tracks to be made. This has been explored, both from the effect of preheat built up by the earlier laser passes, [18, 19] and the effect on the microstructure [10].

In the present work, Ti-6Al-4V plate was laser processed using a combination of SiC powder preplacement and nitriding in a dilute environment. A detailed phase characterisation was undertaken mainly by X-ray diffractometry (XRD) and X-ray photo electron spectroscopy (XPS) techniques, with the prime objective of identifying the phases present. This was a similar approach to that used in previous work in this field,

[10, 20, 21]. A second aim was to provide a better understanding of the influence of the laser process on the microstructure. It is important to know how the microstructural features vary as a function of depth. For example, many studies correlating microstructure with wear resistance, determine only the details of microstructure close to the surface, and forget that this will be worn away and a new surface, with possibly a different microstructure, will be responsible for the wear resistance at a depth below the surface.

2 MATERIALS AND EXPERIMENTAL METHODS

A combination of laser surface nitriding and alloying with SiC preplacement on Ti-6Al-4V alloy using a 40% nitrogen and 60% argon environment has been carried out using a continuous-wave CO₂ laser. A spinning beam mode was used to produce a ~ 2mm wide melt track using a velocity of spinning of 1500 r.p.m. The laser power was set at 2.8 kW and the specimen velocity at 10 mm/s. A total of 12 laser tracks with 50% overlaps was produced on the surface of the 10 mm thick base alloy.

After the laser surface processing, the specimen was cut transversely to the direction of the laser track. The track cross-sections were prepared by mounting the specimens in the bakelite and grinding and polishing by standard metallographic techniques. The polished specimens were chemically etched in a solution of 2gm NH₄.H.HF, 50 ml methanol, and 100 ml H₂O for a period of 1 minute. After etching, the specimens were cleaned by water and methanol, then dried by blasted air. A Nikon Epiphot projection optical microscope and a JEOL JSM 840A scanning electron microscope (SEM) were used for detailed metallographic studies.

XRD patterns were taken using a conventional diffractometer utilizing CuK α radiation and operated at 40kV and 20mA. A 2 θ scan range from 30° to 80°, in steps of 0.1°/20 secs, was recorded. After performing the XRD experiments on the top surface, the specimens were ground to depths of ~100 μ m followed by 300 μ m, using SiC papers. The different depths corresponded to different layers observed by optical microscopy, and the experiments described above were repeated for each layer. To identify the possible XRD and XPS peaks after laser processing, an untreated specimen, and standard specimens of powders of (a)

commercial high purity titanium nitride, (b) titanium carbide, (c) silicon carbide and (d) titanium silicide, were examined [22]. The error in lattice parameter measurements was estimated to be $\pm 0.001 \text{ \AA}$.

Surface analytical spectra were acquired with a Vacuum Generators Scientific Ltd., Model: ESCALAB MK11 x-ray photoelectron spectroscopy unit. The pressure was typically 9×10^{-9} torr in the analysing chamber. For the excitation of XPS spectra, $\text{MgK}\alpha$ (1253.6 eV) radiation was employed throughout, with the anode operating at an output power of 20mA and 11kV. Photoelectrons were collected at approximately 45° from the specimen surface normal. In this study, the specimens were cleaned in-situ by Ar ion bombardment to remove the natural protective titanium dioxide coating or any surface contamination. The residual carbon contamination line at 284.5eV was used as a datum for the binding energy.

3 EXPERIMENTAL RESULTS

3.1 Microstructure

The external appearance of the Ti-6Al-4V alloy surface after processing using a combination of laser surface nitriding and SiC preplacement, is shown in Fig. 1a. A pale gold colour was observed on the surface indicative of nitriding.

The spinning laser beam resulted in a wider melt zone than that produced under the corresponding laser processing conditions using a stationary beam. However, a consequence of the spinning, which may give a similar result to an oscillating beam, is that the energy density is considerably lower than that obtained from a stationary beam using the same laser conditions. This reduction, coupled with the 50% overlapping, had a significant influence on the microstructures formed in the melt zone during the laser alloying processing. The microstructure of a vertical cross-section shows the melt zone, the heat affected zone (HAZ) and a very flat surface crossing an overlapping area, Fig.1b. A crack at the eighth track was observed. From the vertical cross-section, the crack was found to be elongated along the width of the track, and to penetrate from the surface down to the melt zone, just stopping

before the heat affected zone. Also a number of pores were found. These can be seen in Fig 1b at T2 , ($\sim 30\mu\text{m}$ in size) ,T3 , ($\sim 130\mu\text{m}$ in size) and T5 ,($\sim 50\mu\text{m}$ in size), with a large defect , $\sim 300\mu\text{m}$ in size in T2.

The SEM micrographs show the details of microstructures of the specimen at higher magnification, Fig.2. The top region of the melt pool is shown in Figs. 2a-c. After solidification, the microstructure in this region at track 2, seen in Fig.2a, contains a very thin continuous layer on the surface (A) and small dendrites growing from the surface layer in a direction nearly perpendicular to the surface, (B).

A micrograph from the surface of tracks 6 / 7, Fig. 2b, shows that the very thin continuous surface layer, (A), is still present, and below the surface, a network, (C), consisting of small particles and outlines grains of a size <10 microns. Again, the dendrites, (B), can be seen on the right of the figure. Moving to track 7, Fig. 2c, the surface layer (A) is now discontinuous, and at the lower magnification, the extent of the dendrites, (B), is clear. As in Fig.2b, particles (C) can be seen to have formed at the grain boundaries. Fig.2d shows the microstructure, >300 micron from the surface, the precise depth depending on the location with respect to the beam centre. Here there are no significant dendrites or network compounds, but mainly small needles. The phases formed in the melt zone are related to the laser processing conditions such as laser power, traverse velocity and beam radius. They also varied with depth in the melt zone during laser processing. XRD was used to characterize the phases formed at different depths for two different sets of tracks, which are tracks 1 to 3, and tracks 6 to 8. It was necessary to sample more than one track, because of overlapping and the extent of the x-ray beam diameter.

In a previous study of nitrided-only specimens, [10, 20, 22], three phases, TiN, α' -Ti and possibly $\text{TiN}_{0.3}$ were formed at the surface. The results revealed that the quantity of TiN precipitates decreased with the depth of melt pool. A similar trend was also expected in the present specimens. The melt zone developed by laser alloying with SiC preplaced specimens contained TiC particles (spherical), Ti_5Si_3 networks and α' -Ti phases, in agreement with

earlier work, [24]. The depth of the regions and the densities of these phases in the region depend on the amount of SiC particles alloyed in the specific location, the laser processing conditions and the beam modes used in the processing.

In the present study, the XRD spectra from three positions, the top surface, at a depth of 100 μm and of 300 μm below the surface of tracks 1-3, Fig.3, and tracks 6-8, Fig.4, show very complicated results. The dots \bullet , \blacktriangle , \times , \blacksquare , \blacklozenge in the XRD spectra show the anticipated positions of the peaks for α' -Ti, TiC, Ti_5Si_3 , TiN and $\text{TiN}_{0.3}$. The x-ray spectra in Fig.3a and Fig.4a show that the phases, TiN, TiC, α' -Ti and possibly Ti_5Si_3 and $\text{TiN}_{0.3}$, were formed on the top surface. At a depths of 100 μm below the surface, Fig.3b and Fig 4b, the microstructure consisted mainly of α' -Ti, some TiN, a little TiC, and possibly also Ti_5Si_3 and $\text{TiN}_{0.3}$, while at a depth of 300 μm , Fig.3c and Fig.4c, the microstructure contains mainly α' -Ti, a little TiC, and possibly Ti_5Si_3 and $\text{TiN}_{0.3}$. The spectra in Fig.3 show that the strong intensity of the TiN peaks present at the top surface was decreased significantly at both 100 μm , and 300 μm below the surface. This indicates that the TiN phase was present in the melt zone, but for both sets of tracks 1-3 and tracks 6-8, Fig.4, the concentration decreased with depth, an observation which is consistent with those made for the nitrided-only specimens [10, 20].

3.2 Lattice parameter changes

The lattice parameter changes in the TiN and α' -Ti phases were considered by observing the peak shift for both sets of tracks at the three different melt depths. Other phases, such as TiC, Ti_5Si_3 and $\text{TiN}_{0.3}$ were not analysed due to the closeness of each peak to one or two peaks of a different phase. The changes in lattice parameters are considered to result from the combined effect of the residual stress due to the rapid solidification in the laser processing, and to variations in composition of the phases.

By using the XRD data obtained from the laser processed specimens, the lattice parameter, a , of the TiN phase as a function of depth after laser surface nitriding and SiC preplaced alloying under 40% nitrogen environment, was calculated, and the results are

shown in Fig.5. The lattice parameter, a , of the TiN phase, Fig.5a, for the set of tracks 1-3 increases from 4.241 Å on the top surface to 4.250 Å at the 100 µm depth and reverts to the surface value at 300µm. However, for the set of tracks 6-8, a of the TiN phase drops from 4.235 Å at the surface to 4.232 Å at 100µm and rises to 4.4250 Å at 300µm.

The lattice parameters, a and c , of the α' -Ti for both sets of tracks, 1-3 and 6-8 are given in Figs.5b and c. For tracks 1-3, the lattice parameter a of α' -Ti increases from 2.906 Å at the top surface to 2.915 Å at the 100 µm depth and then 2.916 Å at the 300 µm depth. However, the lattice parameter, c , of the α' -Ti, increases from 4.612 Å at the top surface to 4.662 Å at both the 100 µm and 300 µm depths. For the tracks 6-8, a has similar values to those of tracks 1-3, but then increases to 2.924 Å at 300 µm depth. On the other hand, the lattice parameter c is constant at 4.662 Å with depth for tracks 6-8. The increase of a of α' -Ti with depth in the top surface resulted from the combined effect of the formation of TiN, TiC, the influence of Si and N in solid solution, and also the possibility of an effect of the residual stress exists. Zergioti et al [25] have also reported the shifting of XRD peaks due to the presence of the residual stress, in their work on TiB and TiC thin layers produced by pulsed laser deposition.

3.3 Surface analysis by x-ray photoelectron spectroscopy

A wide range scan of 0-500eV, as shown in the example in Fig.6a, was used for all the initial surveys of the samples to identify the elements present. Detailed scans, as in Figs. 6b to e, were then performed over the binding energy ranges of interest. For high intensity peaks, the accuracy of locating relative peak positions is ± 0.1 eV. For low intensity peaks, the peak positions are not so well defined and the accuracy can decrease to ± 0.5 eV. The specimens were cleaned with methanol before inserting into the spectrometer. The XPS spectrum before argon ion sputtering (cleaning), was dominated by surface oxygen and carbon contamination, which obscured the spectrum from the alloy. The ion sputtering removed the oxide layer, and the XPS spectrum showed the presence of titanium nitride.

The XPS spectra of the Ti2p core levels for the processed alloy at different depths taken again from tracks 1-3 and 6-8, are shown in Fig. 7. Table 1 and Table 2 give the values of the binding energy of Ti2p_{3/2} and N1s peaks, and their binding energy difference at different depths taken from tracks 1-3 and tracks 6-8, respectively. The peaks of Ti2p_{3/2} at 454.2 eV, in Tables 1 and 2, correspond to TiN (454.4 eV [26]). At the depth of 100 μm and 300 μm for tracks 1-3, and at the depth of 300 μm for tracks 6-8, the Ti2p_{3/2} peaks approached the base alloy value at 453.6 eV, which correspond to titanium (453.8 eV [27], 453.6 eV [28]). All N1s peaks at the top surface and at the 100 and 300 μm depths for both sets of tracks, correspond to nitrides, which appeared at 396.6 eV [26]. These values confirm the presence of titanium-nitrogen solid solution.

In the C1s spectra, Fig.8, two possible peaks appear. The higher binding energy corresponds to the chemical bonding between Ti and C (labelled TiC), while the lower one is due to absorbed (contamination) carbon (labelled C). The binding energy of the chemical bonding between Ti and C is about 3.0 eV smaller than that arising from the contamination. As mentioned in the literature, the peaks at 280.8 eV for the top surface of tracks 1-3 and tracks 6-8 in the present specimen, indicate the presence of TiC (281 eV [27], 281.5 eV [29] , 81.7 eV [30],). The Si2p XPS core level spectra are shown in Fig.9. There is little evidence for Si on the top surface but a distinct signal appears at 100 μm and at 300 μm for both tracks 1 – 3 and tracks 6 –8. In a similar study with SiC preplacement only [22], the Si 2p signal was apparent from the top surface downwards which implies that in the combined laser treated specimen, the nitriding rejects the Si phase from the surface. The binding energy of the Si 2p peaks in Fig.9 are at 98.4 eV, while the binding energy from the Ti₅Si₃ standard was at 99.2 eV and that from pure Si is at 99.7 eV [29], indicating that the Si containing phase is not pure Ti₅Si₃.

4 DISCUSSION

4.1 Microstructure

The results from the nitriding-only and the SiC preplaced specimens [10, 20, 22], were used as a basis for characterising the phases formed after laser processing using the combination of nitriding and SiC powder preplacement.

Titanium nitride has gold colour, and the track surfaces previously have been observed to exhibit gold and yellow colours when melted in pure and dilute nitrogen environments respectively [4,5]. In the present investigation, surface alloying with silicon carbide in the 40% nitrogen environment, produced a pale golden colour on all the overlapped tracks. This is normally taken as an indication of the formation of a titanium nitride phase in the top surface of melt zone.

The vertical cross-sections of all tracks produced on the Ti-6Al-4V surface in the 40% nitrogen environment gave a melt zone almost free from any SiC particles, which had dissolved after melting. No large SiC particles, picked up from the grinding technique used to produce a new surface, were observed in this work. However, in Fig 1b a defect some 300 μ m in size can be seen at T2, and several pores are present at the melt/ heat affected zone (HAZ) interface. While ideally, macro-defect free microstructures are desirable, these laser processed surfaces were developed to give improved wear and erosion resistance [15, 17, 31]. The presence of porosity, probably due to nitrogen gas quenched into the melt pool, at the interface, had no effect on the surface properties in this work. The crack observed at the eighth track is a more serious defect. However, in previous work, cracking has been overcome by changes to the laser processing procedures, which have included preheating the substrate, and this approach could be used in future work.

The microstructure after solidification in this specimen contained a very thin layer on the surface and small dendrites growing from the surface layer in a direction nearly perpendicular to the surface. The layer was continuous on the surface of tracks 2, Fig.2a, and 6/7, Fig.2b, but was discontinuous for track 7, Fig.2c. This shows an obvious difference from the nitriding only processing where the top TiN compound which always formed a continuous layer, and the dendrites, which had long arms projecting into the melt below the surface [18]. Fig.2a shows some isolated particles formed both in the grains of the matrix and

at the grain boundaries. A network of a compound was formed in the melt pool, spreading between the small grains (<10 μm in diameter) of the matrix and appearing with a eutectic morphology.

Below the top region, particularly at a depth of $\geq 300 \mu\text{m}$ from the surface, there are no significant dendrites or network compounds, but mainly small needles. In the nitrided only specimens, a needle phase has been identified as $\text{TiN}_{0.3}$, which has the same crystal structure and similar lattice parameters of those of α -Ti. The difference is that in the present processing, this needle phase formed only in the region far from the surface, whereas the needles studied previously in the nitriding only process formed throughout the melt zone [20, 21].

4.2 X-ray diffraction

4.2.1 Surface layer

In the above discussion, the existence of a thin layer in the top region, seen in Figs 2a, 2b and 2c, was mentioned. It is clear from the results of the XRD experiments, that the thin layer on the top surface is a primarily a cubic TiN compound. By comparing EDX spectra from the thin layer and from the matrix, [18], it is suggested that the surface is no longer a simple TiN compound, but a TiN solid solution containing carbon and silicon, although the lattice parameters of the phase are unchanged. The matrix is considered to form from the $\beta \rightarrow \alpha'$ martensitic transformation, where the α' -Ti has the same structure and lattice parameters as the α -Ti.

4.2.2 Small dendrites

As the surface XRD spectra show strong TiN and α' -Ti peaks and the quantity of the small dendrites was fairly high, the small dendrites growing in non-preferential directions in the top region must be also the TiN solid solution with dissolved carbon and silicon. An electron back-scattered pattern (EBSP) from this dendrite performed by Hu et al [24] showed a face centred cubic (fcc) structure. This is consistent with the XRD data which contained the

TiN phase with a f.c.c. structure. The thin surface layer and the many small TiN dendrites disconnected from the surface TiN layer are attributed to the addition of SiC particles on the surface before the nitriding. First of all, while some nitrogen would be expected to diffuse between the solid preplaced SiC particles, nitriding would not proceed quickly until the SiC powder coating dissolved into the melt to allow the nitrogen to react with the liquid surface. However, the priorities for the formation of TiN particles at the surface will depend on the opportunities for contact between the liquid and nitrogen. Secondly, even after the SiC particles dissolved into the melt, the TiN solid solution could not grow directly from the surface in the form of long arm dendrites because of an insufficient nitrogen concentration and concentration gradient in the liquid. In addition to this, when the convection flow in the melt is considered, the discontinuous small TiN dendrites formed in the top region would be transferred to a deeper location in the melt, to form the morphology shown in Fig.2d.

4.2.3 Isolated particles and network compound

The volume fraction of the isolated particles is obviously too small to be detected by the XRD technique. Though the quantity of the network compound may be detectable by XRD when the compound is a eutectic mixture and the major phase in the eutectic is the α' -Ti, the quantity of the other phase in the eutectic might still be revealed by the XRD spectrum. Another difficulty in attempting to ascertain the correct peaks for TiC or Ti_5Si_3 is the closeness of other strong peaks. Hu et al [24] suggested, following analysis of EDX spectra, that the isolated particles are a carbon rich phase and the network compound at grain boundaries is a silicon rich phase. Consideration of the Ti-C and the Ti-Si phase diagrams suggests that the isolated particles are most probably a TiC phase and the network compound, Ti_5Si_3 phase. XRD results from the top surface and below 100 μm from surface show the possibility of the existence of the TiC particles and a Ti_5Si_3 compound.

4.2.4 Needle phase

In earlier work of Hu et al [20], a needle phase in the nitriding only processing was identified as $\text{TiN}_{0.3}$. This phase has the same crystal structure (hexagonal) as the α' -Ti phase

and has similar lattice parameters. Also found in this earlier work was that the lattice parameters of the $\text{TiN}_{0.3}$ phase changed with a change in those of α' -Ti. Using XRD, these investigations found the following lattice parameters in a commercial purity titanium alloy, $a=2.9511\text{\AA}$ and $c=4.6843\text{\AA}$ for the α' -Ti and $a=2.976\text{\AA}$ and $c=4.807\text{\AA}$ for the $\text{TiN}_{0.3}$ phase. However, in a Ti-6Al-4V alloy studied in the same work [20], it was found that $a=2.925\text{\AA}$ and $c=4.670\text{\AA}$ for the α' -Ti and $a=2.941\text{\AA}$ and $c=4.727\text{\AA}$ for the $\text{TiN}_{0.3}$ phase. A further XRD analysis was carried out in this region in the present work, by removing $300\text{ }\mu\text{m}$ from the surface. The results in Fig.4c and Fig.5c show there are no additional strong peaks present from this region, but only those associated with the α' -Ti and $\text{TiN}_{0.3}$ phases. Thus, the needle phase in the present work is considered to be the $\text{TiN}_{0.3}$ phase, which has the same structure as the α' -Ti phase with similar lattice parameters, but a higher nitrogen concentration.

4.2.5 Lattice parameter changes

Fig 5 shows the changes in lattice parameters of both TiN and α' -Ti with depth below the processed surface for tracks 1-3 and 6-8. In the transition elements, the cubic nitrides can exist in a wide range of non-stoichiometry, and FCC TiN_x can be obtained with $0.5 \leq x \leq 1.1$ [32]. For slowly cooled specimens, TiN_x has a lattice parameter which increases linearly from 4.215\AA , when $x=0.6$, to a maximum of 4.242\AA , when $x=1$ [32, 33] and then decreases linearly to 4.225\AA when $x=1.1$ [32]. Furthermore, most of the transition metal carbides and nitrides are mutually soluble, forming a series of carbonitrides which have face-centered cubic (FCC) NaCl crystal structures [34, 35]. The lattice parameter, a , for TiC is given as $4.312\text{-}4.315\text{\AA}$ [36], 4.294\AA [22] and 4.33\AA [37], all of which are significantly greater than the maximum a for TiN. The lattice parameter of the carbonitrides behaves linearly between TiN-TiC [34].

In a previous paper by Selamat et al [10], discussing laser nitriding using 20%N, it was found that for tracks 1-3, a increased from 4.213\AA at the surface to 4.222\AA at a depth of

100 μm , while for tracks 6-8, a remained constant at 4.222 \AA . This indicated that x was always <1 . TiN was not detected below 100 μm . In the present work, which used 40%N, the variations in a , as determined by XRD, and shown in Fig5a, can be explained by the different C, N and Si contents of $\text{Ti}(\text{C}_y, \text{N}_x)$, with Si in solid solution. a is always \geq than 4.23 \AA , indicating that in a TiN_x C and Si free phase, x is ≥ 0.9 . C diffuses $\sim 17x$ faster than N in βTi at 1423K [38, 39] (the difference in diffusion coefficients in the liquid state is not known). In tracks 1-3 the increase in a between the surface and 100 μm , may be associated with the presence of C in TiN solid solution, while the decrease in a between 100 and 300 μm could be due to the limitations in the diffusion of C and N, in the latter case, 300 μm depth, resulting in a smaller values of x and y in $\text{Ti}(\text{C}_y, \text{N}_x)$. It should be remembered that nitrogen has to penetrate the SiC layer before reacting with the Ti-6Al-4V alloy.

The lattice parameters of the α phase in slowly cooled or aged Ti-6Al-4V are $a = 2.925\text{\AA}$ and $c = 4.670\text{\AA}$ [39]. These parameters are similar for α' [40], which are smaller than the lattice parameters of CPTi, given as $a = 2.951\text{\AA}$ and $c = 4.684\text{\AA}$, by Wriedt and Murray [32], and included in Figs5b and 5c. It is considered that the substitutional elements in solid solution in α/α' , Al and V, are responsible for the decrease in the lattice parameters. Both these elements and silicon have smaller atomic diameters (2.86 \AA , 2.63 \AA , 2.35 \AA) than titanium (2.95 \AA). On the other hand, the interstitial elements C, N, and O are known to increase the lattice parameters of the α phase [20,40]. It is noted for tracks 6-8, that c is unchanged, probably due to preheat producing slower cooling and allowing a closer approach to the equilibrium lattice parameter value. This effect only appears for a in tracks 1-3, at 300 μm depth, as the smaller a value of the surface persists to 100 μm . The XPS results suggest that Si is rejected from the surface but is present in TiN_x solid solution at 100 μm and 300 μm subsurface. Hu and Baker [41] showed that overlapping 11 tracks could result in a preheat of up to 290 $^\circ\text{C}$ during laser nitriding with 20%N, recorded in 10mm thick Ti-6Al-4V plate. It is considered that even higher temperatures could result through the exothermic reaction to form TiN from the use of 40%N. This could result in greater distances in the diffusion of both N

and C below the surface, albeit at lower and lower concentrations, which might explain the increase in a seen in Fig5a for tracks 6-8.

While the residual stress will have an effect on a , it would be expected that the preheat generated by the melting of a number of tracks, would have a major influence in reducing the residual stress level throughout the work-piece.

There are few experimental data in the literature concerning the residual stress levels developed in laser surface processing [14, 42]. Ubhi et al [42] showed that the residual stress across a single track in laser glazed Ti-6Al-4V plate was +170MPa compared to +100MPa (+ve is tensile) in the parent plate, and these values were reduced by annealing. Mridha et al [14] determined the residual stresses in single track laser processed using 3mm thick CPTi sheet, alloyed with $\sim 6\mu\text{m}$ SiC particles. They showed that the tensile stresses determined parallel to the track direction, decreased with depth from +259MPa at the surface to +124MPa at a depth of 200 μm . The compressive stresses determined perpendicular to the track direction, also decreased from the surface -244MPa to -170MPa at 100 μm subsurface, to -99MPa at 200 μm subsurface. How the effects of the combined tensile and compressive stresses would affect the local lattice parameters of TiN and α' -Ti has not been determined. However, the residual stresses in tracks 6-8 would be expected to be reduced significantly through the preheat developed in this work..

4.3 X-ray photospectroscopy

XPS results have suggested that with the present specimen, the surface is no longer a simple TiN cubic compound, but a TiN solid solution containing carbon and silicon, possibly a carbonitride. Further, it is thought that the small dendrites growing in non-preferential directions in the top region, Fig 2a, must also be the TiN solid solution with dissolved carbon and silicon. It is considered that the needle phase, Fig 2d, is most likely to

be the $\text{TiN}_{0.3}$ phase, while the region below 300 μm from surface is associated with the α' -Ti and $\text{TiN}_{0.3}$ phases.

Comparison of the binding energy difference (ΔE) between the $\text{Ti}2p_{3/2}$ and the $\text{N}1s$ core peaks, Table 1 and Table 2, with the work of Porte et al [43], Fig. 10, suggests that in the present specimen, $x \approx 0.65-0.8$ in TiN_x . This range compares well with that of a 20% nitrogen Ti-6Al-4V alloy, where for similar experiments, $x \approx 0.5-0.8$ [10]. The atomic fraction of C was not assessed.

In the $\text{C}1s$ core level spectra, Fig.9, the peak at about 280.8 eV binding energy, is due to the chemical bonding between Ti and C (labelled TiC) and that at about 284.5 eV represents absorbed carbon. These results indicate that a certain amount of TiC and unreactive sources are contained in the specimens. For the layer showing strong TiC peaks, the absorbed carbon is noticeably reduced and the chemical bonding of Ti-C dominates.

The $\text{Si} 2p$ spectra of Figure 9 show that the silicon concentration is too low to produce a discernable signal from the surface. However, such a signal does appear at the 100 μm and the 300 μm depths for both sets of tracks indicating that the silicon has diffused from the surface into the depth of the melt pool. In the earlier study with SiC preplacement only, [22], Si was present from the surface downwards so it would appear that the presence of nitrogen in solution at high concentrations has the effect of rejecting silicon. Since the microstructure at these depths shows only α' -Ti and the needle phase $\text{TiN}_{0.3}$, the silicon must be in solid solution.

4.4 Comparison with recent significant studies

With the exception of the work undertaken at Strathclyde University [22-24] there are few publications concerned with Ti-6Al-4V alloys where SiC particles dissolved during laser processing, and which discuss the microstructure in depth. Furthermore, there appears to be no other published work on laser nitriding Ti-6Al-4V combined with alloying with SiC additions [44]. However, Pei et al [45] have studied in detail the microstructure in single

track Nd:YAG laser processed Ti-6Al-4V alloys without nitriding, into which 50-90 μ m SiC particles were injected, using beam scanning velocities in the range 8.3 to 13mm/s, which spanned that used in the present work.

Like the present work, they also found a variation in the microstructure with depth, but in their case, the presence of undissolved SiC particles had a major influence on the morphology of the submicron phases [45]. For example, a heterogeneously nucleated TiC reaction layer was always found to surround the SiC particles. This was sometimes associated with Ti₅Si₃. A eutectic of TiC/ α -Ti was also observed. The thickness of the reaction layer was shown to be influenced by the beam velocity and the depth to which the SiC had penetrated. The same phases were also identified by Oh and Lee [46] in surface composites developed by melting powders of TiC, SiC or mixtures of both, on Ti-6Al-4V alloys using high energy electron beam irradiation. One major difference to the microstructure recorded by both these sets of workers [45,46] to that observed by Selamat et al [22], was the absence of a thin surface layer comprised of Ti_{0.55}C_{0.45}, Ti₅Si₃ and a martensitic α' -Ti solid solution containing Si and/or C. In the case of the combined SiC plus laser nitriding studied here, this is replaced by a thin layer of TiN solid solution containing C, possibly forming a carbonitride, and Si, plus martensitic α' -Ti.

5 CONCLUSIONS

A combination of laser surface nitriding and alloying with SiC preplacement on a Ti-6Al-4V alloy using a 40% nitrogen and 60% argon environment has been carried out and produced a pale gold colour on the surface after laser processing. The spinning beam mode was used to produce a 4mm wide melt track using a velocity of spinning of 1500 r.p.m. for the main specimens studied in this work. The laser power was set at 2.8 kW and the specimen velocity at 10 mm/s. A total of 12 laser tracks with 50% overlaps produced a 24mm wide modified surface on the 7mm thick base alloy.

Following the study of characterization of the Ti-6Al-4V alloy using SEM, XPS and XRD, a phase identification was made, and the following conclusions were reached:-

(1) a spinning beam associated with overlapping tracks produced a smoother and a uniformly thick melted layer (more than 300 μ m deep) over a significant area, compared with a stationary beam melting a single track.

(2) XRD spectra from the specimens taken from tracks 1-3 and 6-8, showed similar features. At the surface, cubic TiN (possibly a carbonitride) was prominent, while TiC and α' -Ti, were identified, and Ti₅Si₃ and TiN_{0.3} were also possibly present. At depths of 100 μ m, cubic TiN was less concentrated. With increase in depth, α' -Ti became more prominent, while the other phases were still in evidence. The results suggest that the surface layer comprised mainly of a cubic TiN solid solution containing C, (possibly a carbonitride), and Si.

(3) XPS data suggest that the cubic TiN solid solution containing carbon and silicon is in fact non-stoichiometric ie, TiN_x, where x lies between $0.65 \leq x \leq 0.8$. The evidence for Si on the top surface is only slight but a distinct signal appears at 100 μ m and at 300 μ m for both sets of tracks. In a similar study with SiC preplacement only [22], the Si 2p signal was apparent from the top surface downwards. This implies that in the combined laser treated specimen, the nitriding rejects the Si phase from the surface.

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Tables

Table 1 : The binding energies (eV) of the Ti2p_{3/2}, N1s and their differences with depths for tracks 1-3.

Depth (μm)	Ti2p _{3/2}	N1s	Ti2p _{3/2} - N1s
0	454.2±0.1	396.2±0.1	58.0±0.4
7.5	454.2±0.1	396.4±0.1	57.8±0.2
100	454.1±0.1	396.1±0.1	58.0±0.2
300	453.6±0.1	396.1±0.1	57.8±0.2
Base alloy	453.6±0.1	-	-

Table 2 : The binding energies (eV) of the Ti2p_{3/2}, N1s and their differences with depths for tracks 6-8.

Depth (μm)	Ti2p _{3/2}	N1s	Ti2p _{3/2} - N1s
0	454.7±0.1	396.2±0.1	58.0±0.2
7.5	454.2±0.1	396.2±0.1	58.0±0.
100	453.8±0.1	396.2±0.1	57.6±0.2
300	454.4±0.1	396.2±0.1	57.6±0.2
Base alloy	453.6±0.1	-	-

Figure Captions

Figure 1 : (a) Macrograph, and (b) optical micrograph of the laser processed specimen.

Figure 2 : SEM micrographs showing microstructure produced in the laser processed specimen. (a) Top surface of track 2, (b) top surface of track 6/7, (c) top surface of track 7, (d) at a depth of over 300 μm below the top surface of track 1/2.

Figure 3 : X-ray diffraction spectra of the laser processed specimen for tracks 1-3, (a) at the top surface, (b) at the 100 μm depth, and (c) at the 300 μm depth. (■ TiN, ● α' -Ti, ▲ TiC, x Ti_5Si_3 , ◆ $\text{TiN}_{0.3}$)

Figure 4 : X-ray diffraction spectra of the laser processed specimen for tracks 6-8, (a) at the top surface, (b) at the 100 μm depth, and (c) at the 300 μm depth. (■ TiN, ● α' -Ti, ▲ TiC, x Ti_5Si_3 , ◆ $\text{TiN}_{0.3}$)

Figure 5 : The lattice parameters formed at different depths of the laser processed specimen. (a) a of TiN, (b) a of α' -Ti, and (c) c of α' -Ti.

Figure 6 : (a) XPS wide energy range (0-550 eV) survey scan for the laser processed specimen, taken from tracks 1-3. Detailed scans of the core level peaks, (b) Ti2p, (c) C1s, (d) O1s and (e) N1s.

Figure 7 : The XPS spectra of the Ti2p core levels with different depths for the laser processed specimen, (a) from tracks 1-3 and (b) from tracks 6-8.

Figure 8 : The XPS spectra of the C1s core levels with different depths for the laser processed specimen, (a) from tracks 1-3 and (b) from tracks 6-8.

Figure 9 : The XPS spectra of the Si2p core levels with different depths for the laser processed specimen, (a) from tracks 1-3 and (b) from tracks 6-8.

Figure 10 : Binding energy difference (ΔE) between the Ti2p_{3/2} and the N1s core-level peaks versus x obtained from the TiN_x produced using PVD method (31).

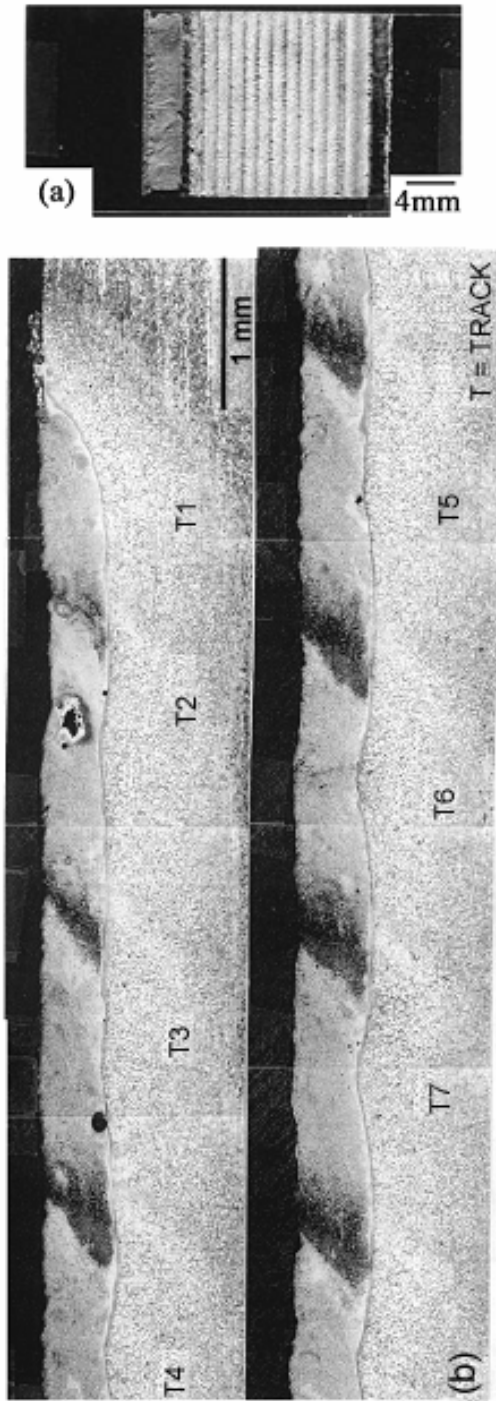


Figure 1

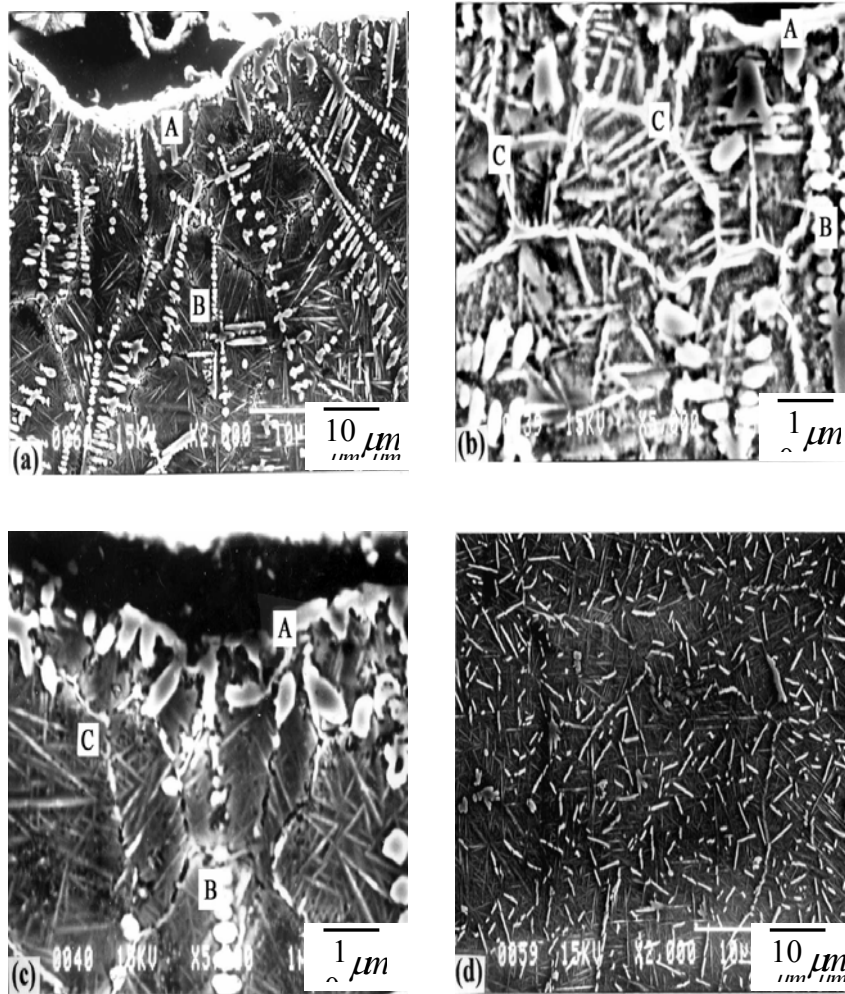


Figure 2

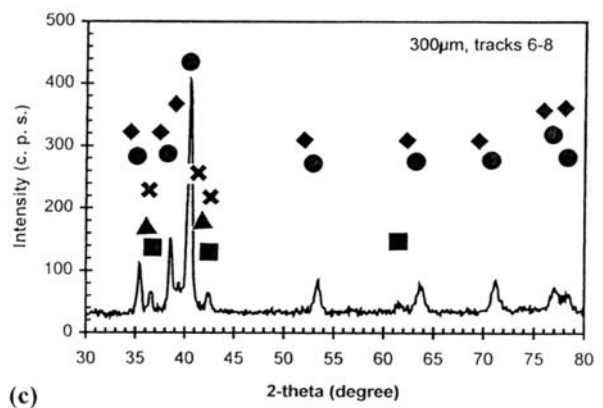
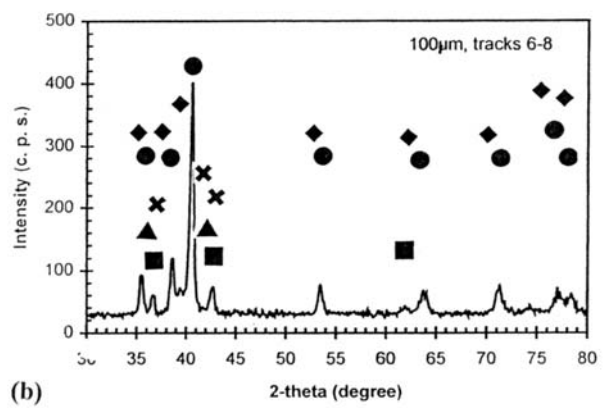
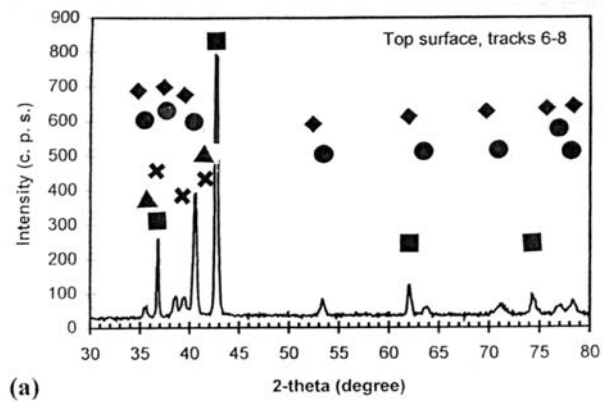


Figure 3

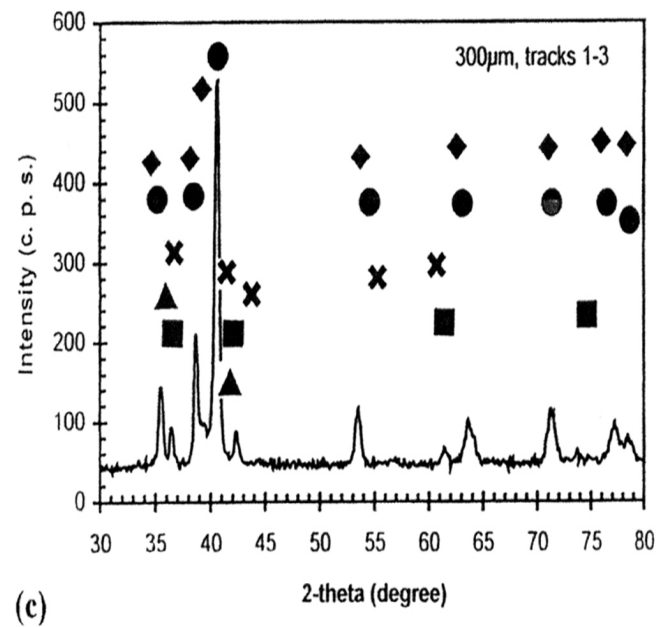
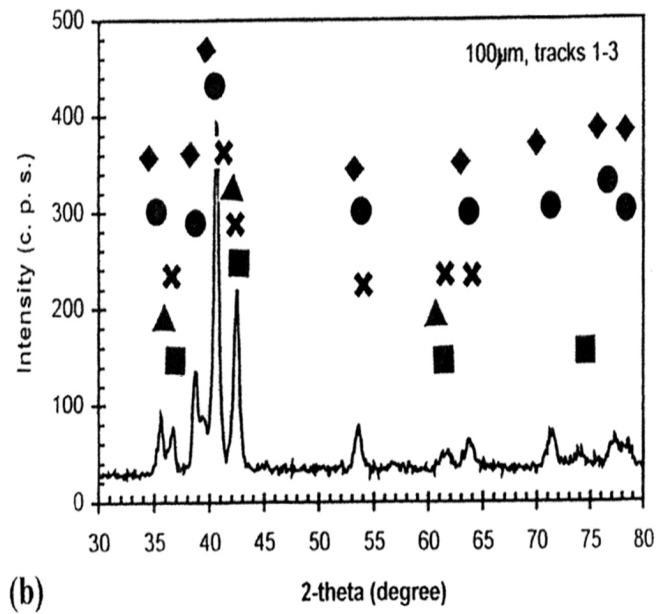
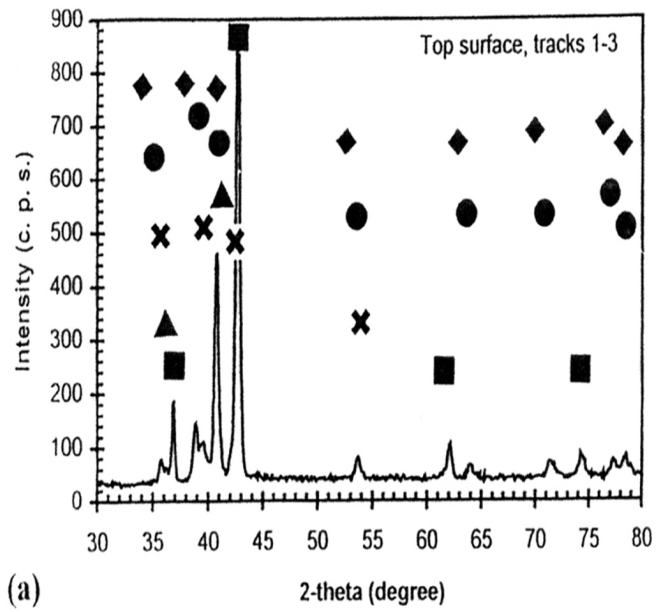


Figure 4

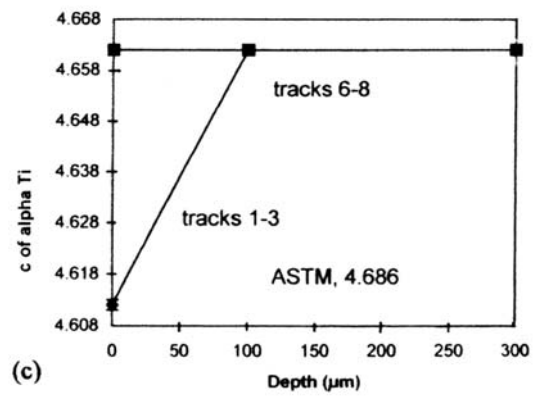
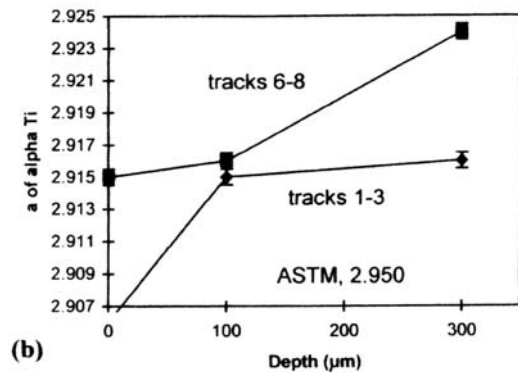
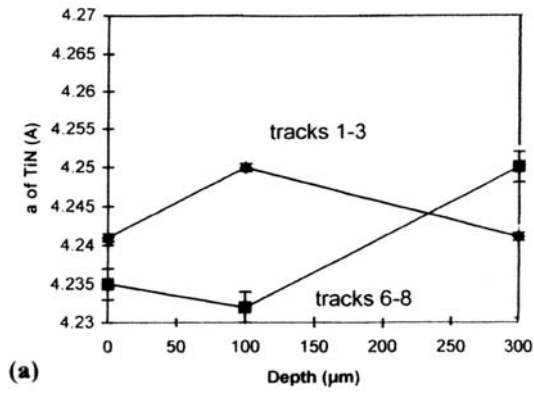
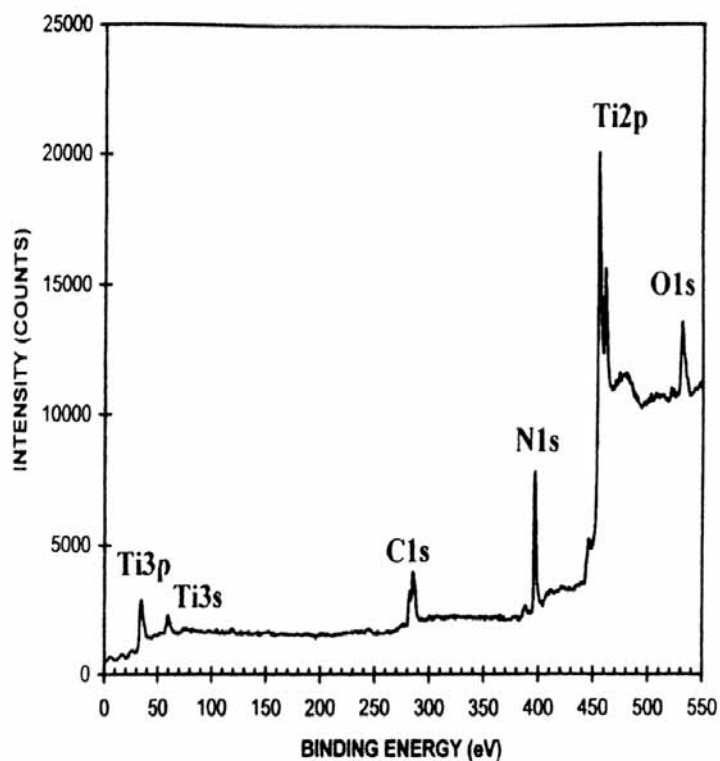
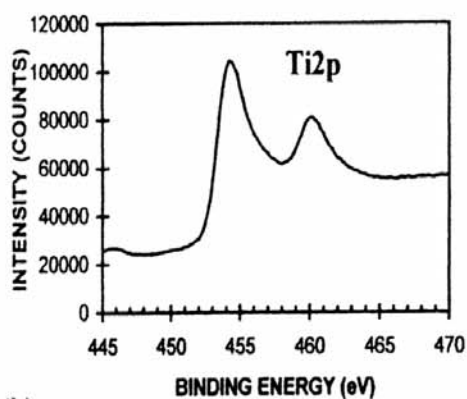


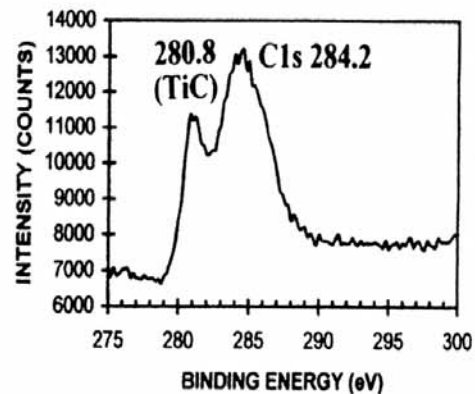
Figure 5



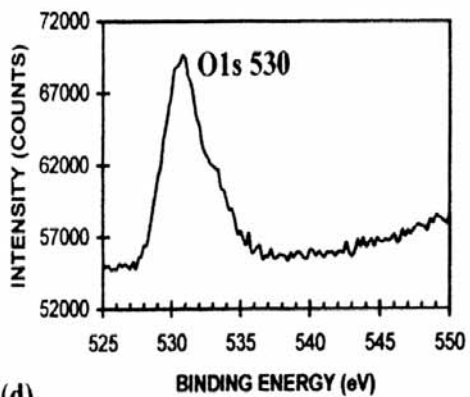
(a)



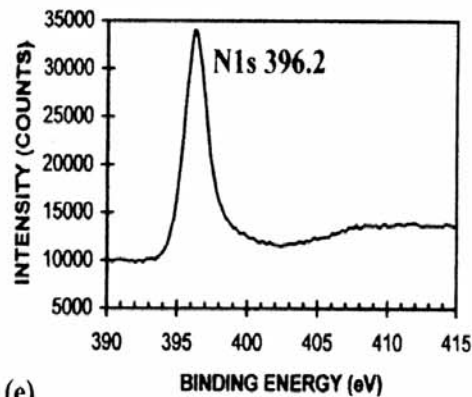
(b)



(c)



(d)



(e)

Figure 6

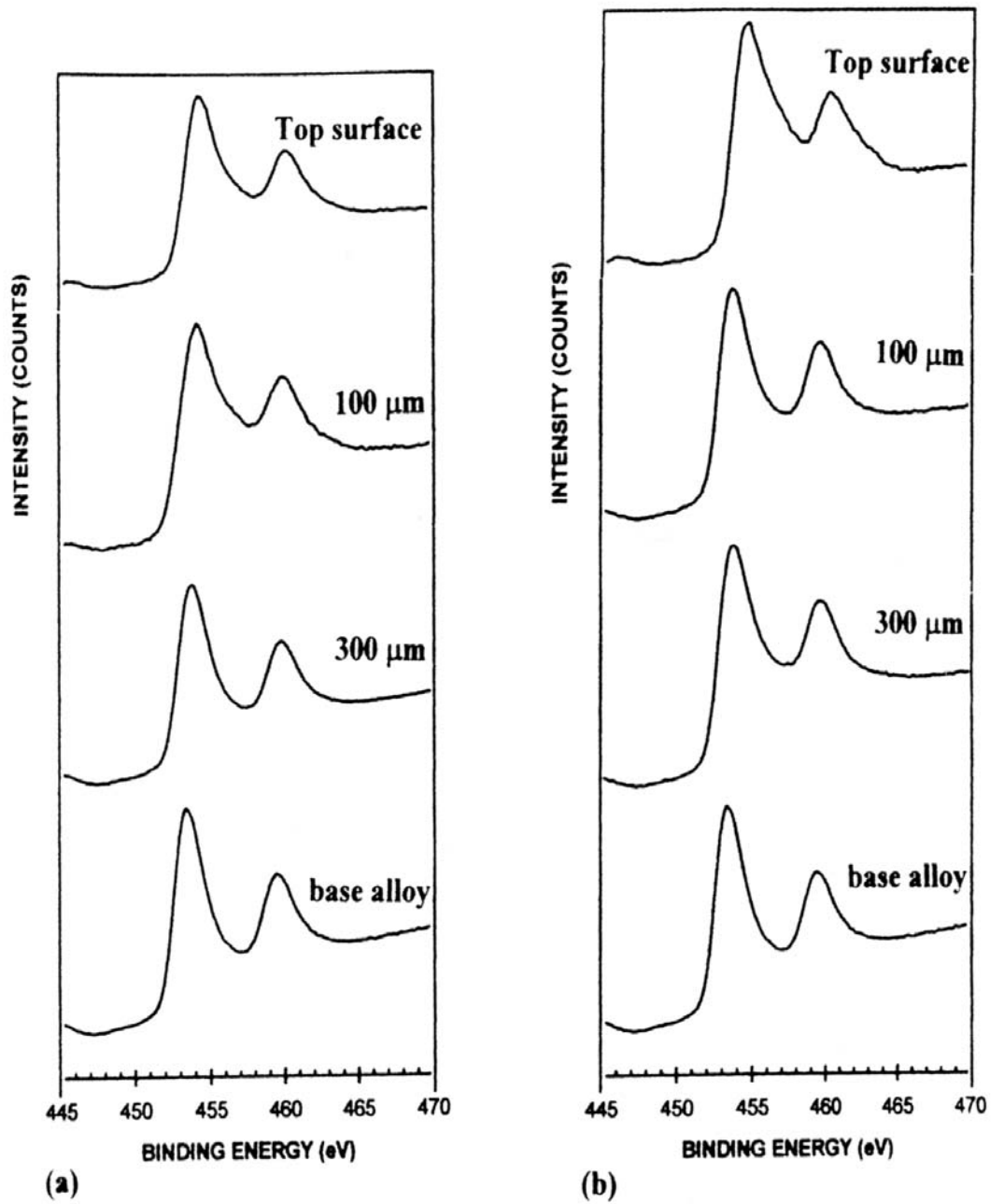


Figure 7

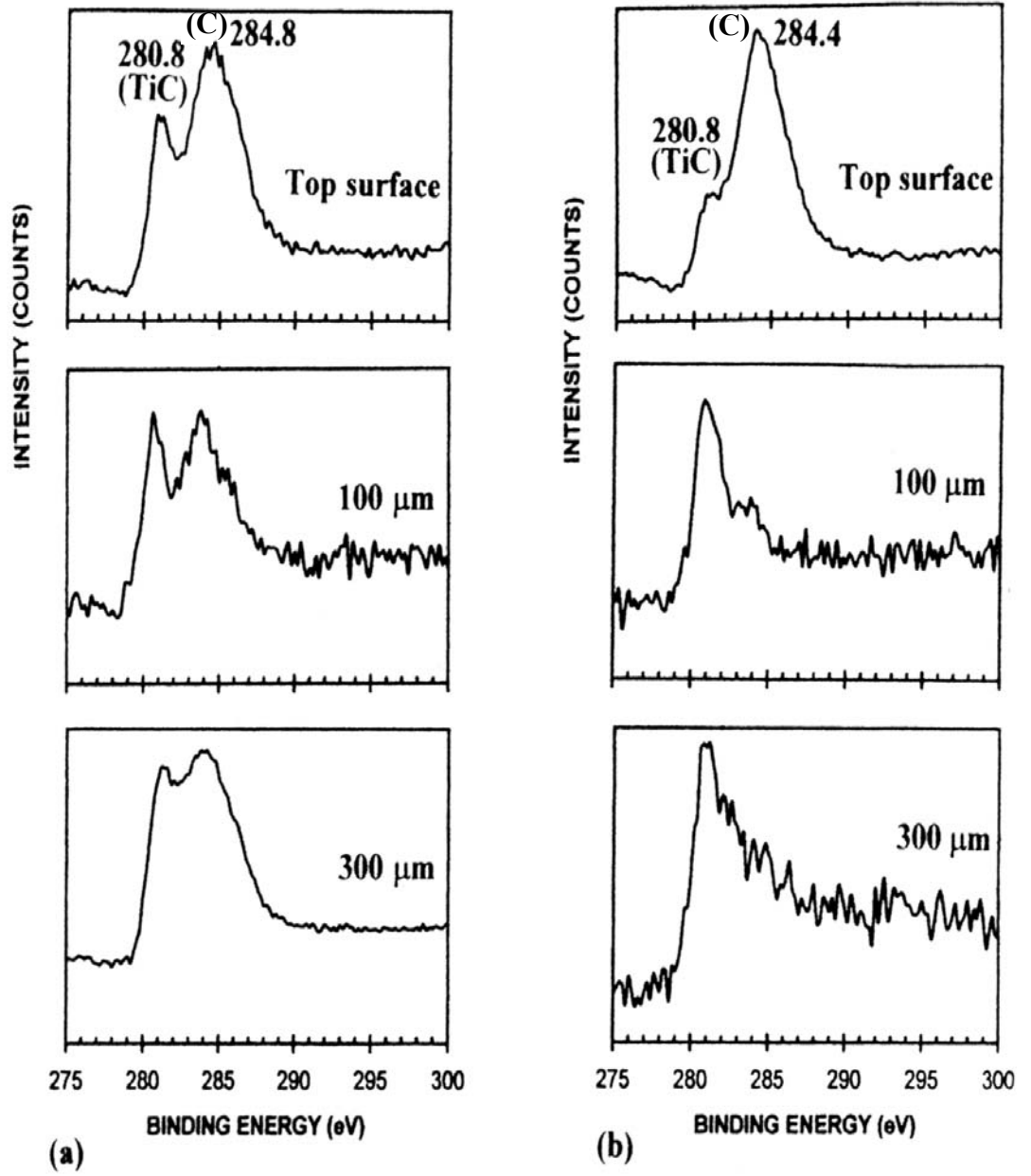


Figure 8

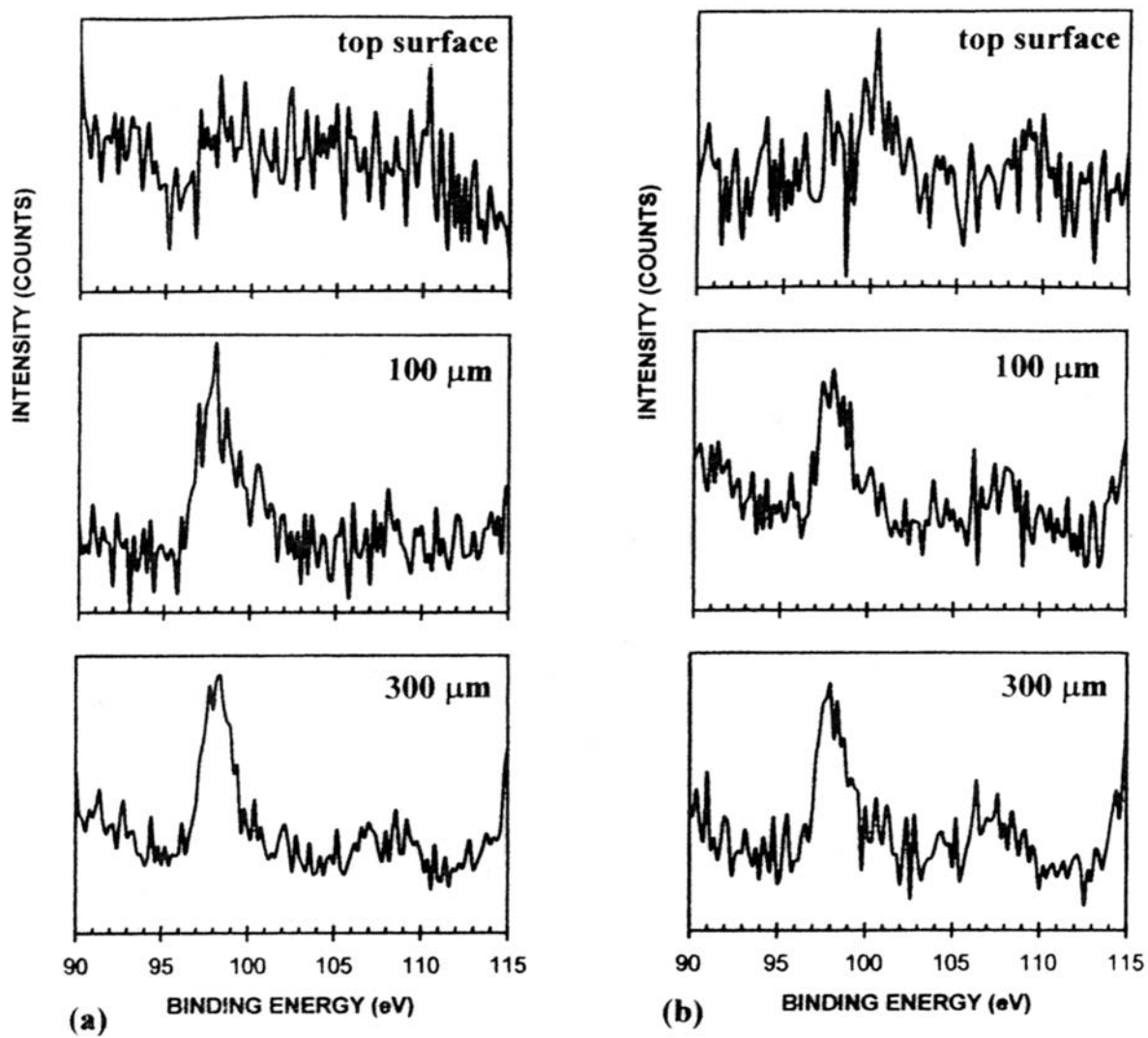


Figure 9

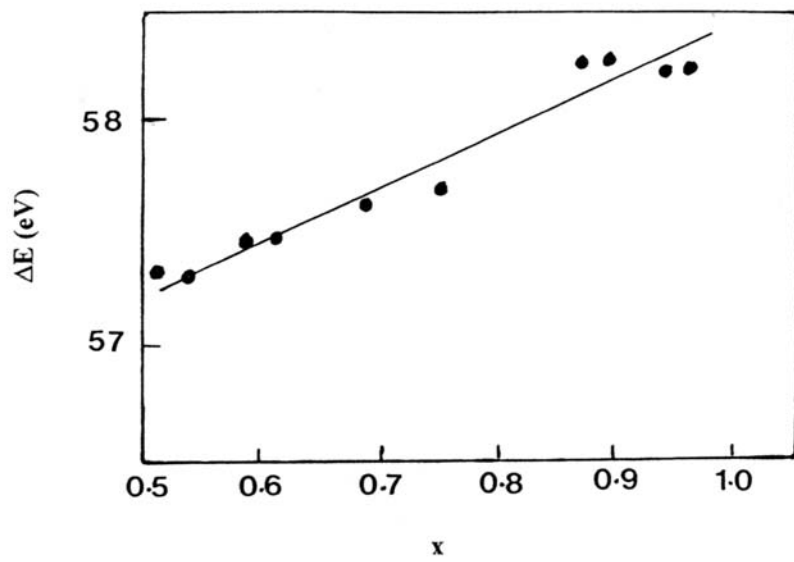


Figure 10

